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## FDC8602 Dual N-Channel Shielded Gate PowerTrench<sup>®</sup> MOSFET 100 V, 1.2 A, 350 m $\Omega$

### Features

- Shielded Gate MOSFET Technology
- Max  $r_{DS(on)}$  = 350 m $\Omega$  at V<sub>GS</sub> = 10 V, I<sub>D</sub> = 1.2 A
- Max  $r_{DS(on)} = 575 \text{ m}\Omega \text{ at } V_{GS} = 6 \text{ V}, I_D = 0.9 \text{ A}$
- High performance trench technology for extremely low r<sub>DS(on)</sub>
- High power and current handling capability in a widely used surface mount package
- Fast switching speed
- 100% UIL Tested
- RoHS Compliant

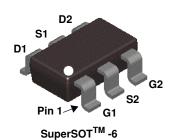


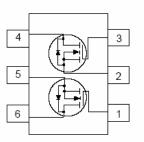
## **General Description**

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench<sup>®</sup> process that incorporates Shielded Gate technology. This process has been optimized for  $r_{DS(on)}$ , switching performance and ruggedness.

## **Applications**

- Load Switch
- Synchronous Rectifier





### MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol			Ratings	Ur			
V <sub>DS</sub>	Drain to Source Voltage				100	,	
V <sub>GS</sub>	Gate to	Gate to Source Voltage				,	
I <sub>D</sub>	Drain Cu	Drain Current -Continuous (Note 1a)					
		-Pulsed	5				
E <sub>AS</sub>	Single P	Single Pulse Avalanche Energy (Note 3)				n	
	Power D	Power Dissipation (Note 1a)				0.96	
P <sub>D</sub>	Power D	Dissipation	0.69	<u>۱</u>			
T <sub>J</sub> , T <sub>STG</sub>	Operatir	ng and Storage Junction T	-55 to +150	) °			
Thermal Cl	haracteri	stics					
$R_{\theta JC}$	Thermal Resistance, Junction to Case				60		
R <sub>0JA</sub>	Thermal	Resistance, Junction to A	130	°C			
Package M	larking a	nd Ordering Inform	ation				
Device Marking		Device	Package	Reel Size	Tape Width	Quantity	
.862		FDC8602	SSOT-6	7 "	8 mm	3000 uni	

www.fairchildsemi.com

May 2013

FDC8602 Dual I
<b>V-Ch</b>
annel Shielded Gate PowerTrench <sup>®</sup> N
MOSFET

Symbol	Parameter	Test Con	ditions	Min	Тур	Max	Units
Off Chara	octeristics						
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250 μA, V <sub>GS</sub> = 0 V		100			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C			73		mV/°C
IDSS	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 80 V, V <sub>GS</sub> = 0 V				1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$				±100	nA
On Chara	cteristics				·		
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 25	0 uA	2	3.2	4	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$ , referenced to 25 °C			-8		mV/°C
r <sub>DS(on)</sub>		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 1.2 A			285	350	mΩ
	Static Drain to Source On Resistance	$V_{GS} = 6 V, I_D = 0.9$		409	575		
		$V_{GS} = 10 \text{ V}, I_D = 1.2$		489	600		
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = 10 V, I_{D} = 1.2 A$			1.3		S
C <sub>iss</sub> C <sub>oss</sub>	Characteristics Input Capacitance Output Capacitance	— V <sub>DS</sub> = 50 V, V <sub>GS</sub> = 0 V, — f = 1MHz			53 17	70 25	pF pF
C <sub>rss</sub>	Reverse Transfer Capacitance				0.8	5	pF
R <sub>g</sub>	Gate Resistance				1.6		Ω
Switching	characteristics						
t <sub>d(on)</sub>	Turn-On Delay Time				3.5	10	ns
t <sub>r</sub>	Rise Time	$V_{DD} = 50 \text{ V}, \text{ I}_{D} = 1.2 \text{ A}, \\ V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$			1.7	10	ns
t <sub>d(off)</sub>	Turn-Off Delay Time				5.4	11	ns
t <sub>f</sub>	Fall Time				2.3	10	ns
Q <sub>g(TOT)</sub>	Total Gate Charge	$V_{GS} = 0$ V to 10 V			1.2	2	nC
Q <sub>g(TOT)</sub>	Total Gate Charge	$V_{GS} = 0$ V to 5 V	V <sub>DD</sub> = 50 V,		0.6	1	nC
Q <sub>gs</sub>	Gate to Source Charge	I <sub>D</sub> = 1.2 A			0.4		nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge				0.4		nC
Drain-Sou	urce Diode Characteristics						
V <sub>SD</sub>	Source-Drain Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 1.2$	A (Note 2)		0.86	1.3	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 1.2 A, di/dt = 100 A/μs			27	43	ns
Q <sub>rr</sub>	Reverse Recovery Charge	1F = 1.2 / , a/at = 1	οο / γμο		12	21	nC



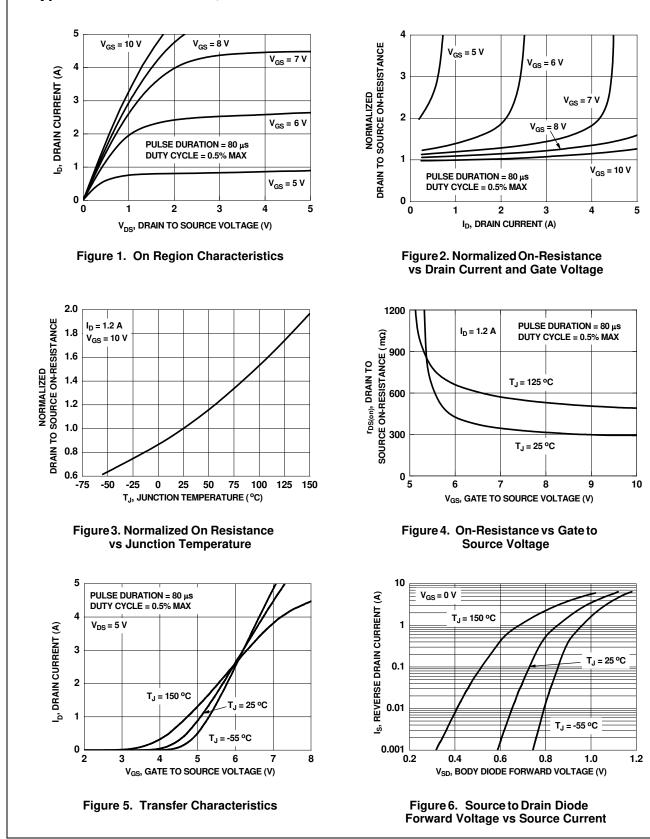
3. Starting  $T_J$  = 25 °C; N-ch: L = 3 mH,  $I_{AS}$  = 1 A,  $V_{DD}$  = 100 V,  $V_{GS}$  = 10 V.

 a) 130 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper



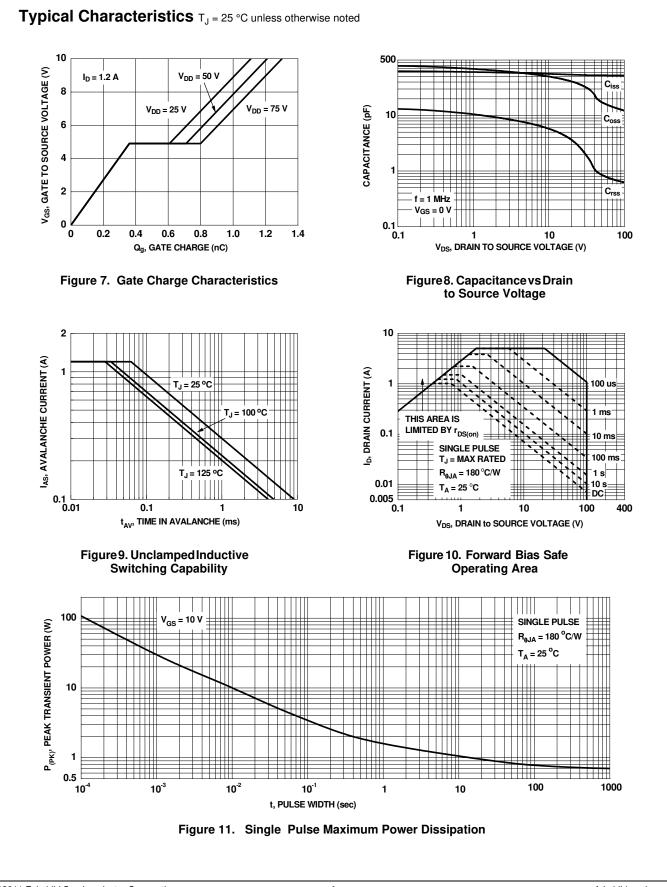
b) 180 °C/W when mounted on a minimum pad of 2 oz copper

2. Pulse Test: Pulse Width < 300  $\mu s,$  Duty cycle < 2.0%.

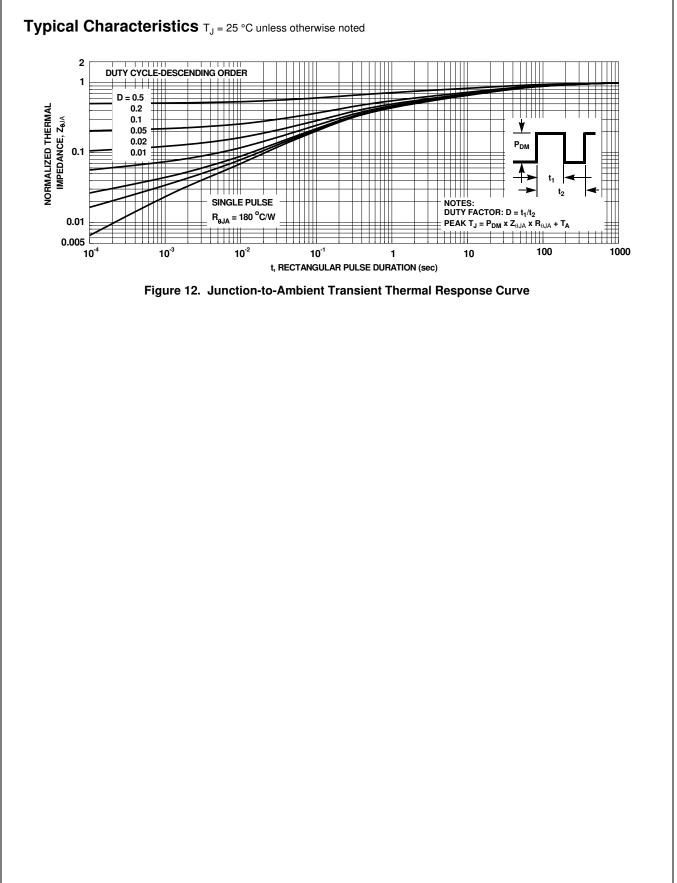


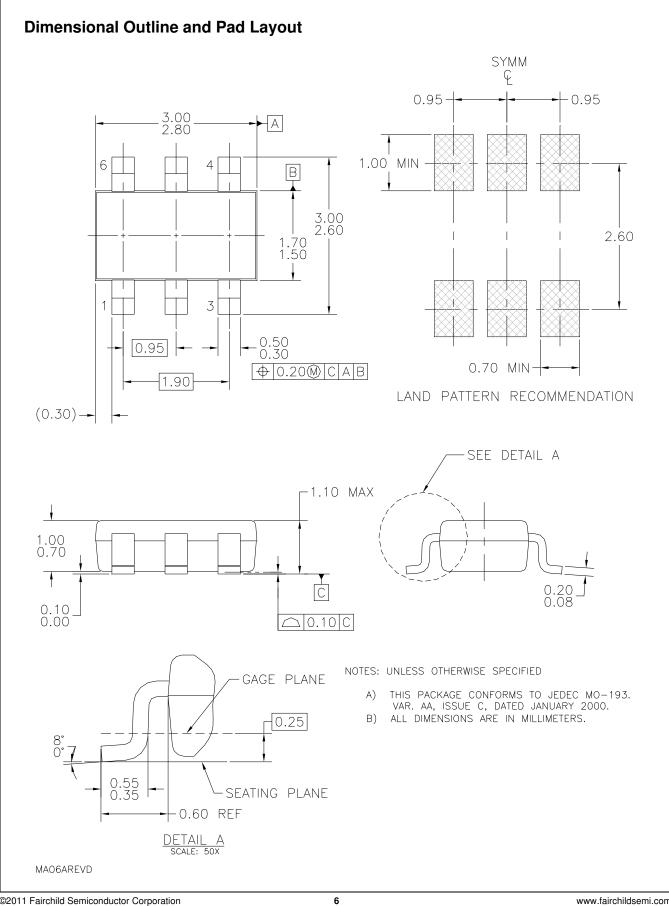
### Typical Characteristics T<sub>J</sub> = 25 °C unless otherwise noted

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